# Anisotropic resonance energy transfer with strained phosphorene

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We analyze the resonance energy transfer (RET) rate between quantum emitters (QEs) near a phosphorene/SiC interface under the effects of uniaxial strain. Using a low-energy tight-binding model, we describe the electronic structure of strained phosphorene in an experimentally feasible situation. Due to the anisotropic electronic structure of phosphorene, we demonstrate that the RET rate drastically depends on the direction in which the QEs are separated relative to the phosphorene lattice. More specifically, we obtain a large variation in the RET rate when the QEs are separated along the zigzag direction, in contrast to a rather small variation when separated along the armchair direction of phosphorene's crystalline structure. Furthermore, our results reveal that the RET rate can be highly modulated by uniaxial strain in phosphorene when considering emitters placed along the zigzag direction. Finally, by means of a simple toy model, we also show that this anisotropy in the RET rate is a general characteristic produced by anisotropic 2D materials.

# I. INTRODUCTION

Quantum electrodynamics, which describes radiationmatter interactions, is one of the most precise theories in physics, as the agreement between theoretical predictions and observed experimental data has achieved an unprecedented level [1–3]. It can be used to describe processes not only in high-energy particle physics but also in lowenergy scales, such as when non-relativistic atoms interact with the radiation field in its vacuum state. These latter processes are usually referred to as quantum vacuum effects [4].

The omnipresence of the vacuum electromagnetic field gives rise to various interesting and unexpected phenomena [5–8], including the so-called resonance energy transfer (RET) [9–11]. The simplest system in which RET typically occurs is constituted by two closely spaced atoms, one excited and the other in the ground state, where the radiation field has no excitations (i.e., no photons). Since this initial state is not an eigenstate of the total Hamiltonian, it will inevitably evolve in time, leading to a nonvanishing probability of finding another configuration in which the excitation energy from atom  $\mathcal{A}$ will be transferred to atom  $\mathcal{B}$  without photon emission.

RET is a phenomenon historically related to biology and chemistry. The discovery of RET by the German physical chemist Theodor Förster [12] was in the context of light-sensitive molecules while studying the unexpectedly high efficiency of photosynthesis. More recently, the ability to harness RET has become a sought-after goal due to its wide range of applications, such as the engineering of photo and biosensors [13–18], spectroscopic nano-rulers [19–21], supramolecular systems [22–24], luminescent solar concentrators [25–27], among many others [28–31]. Over the last few decades, great theoretical advances and technological developments in nanoplasmonics and nanophotonics have allowed astonishing control of radiation-matter interactions at increasingly smaller scales. This feat can be achieved by changing the neighborhood of the quantum emitters (QEs), which alters the boundary conditions of the vacuum electromagnetic field modes [32–39]. Particularly, this strategy has been extensively used for controlling RET, as shown in Refs. [10, 40– 46].

In this sense, 2D materials stand out from conventional ones due to their highly flexible electronic properties, which reveal unique light-matter coupling behaviors [47, 48]. Numerous nanophotonic effects in 2D materials are being studied theoretically and experimentally, including the physics of dispersive forces [49–55], near-field effects in QEs [43, 44, 56–59], and heat transfer [60–63], to mention a few. The ever-growing class of these materials holds significant promise for future practical applications.

Phosphorene, a monolayer of black phosphorus first synthesized in 2014 [64, 65], has since become a particularly attractive 2D material for nanophotonic applications [66], as its electronic band structure presents a direct bandgap [67, 68] that can be controlled by uniform strain [69–71]. Furthermore, phosphorene exhibits anisotropic conductivity properties that enable rich physics, including the presence of hyperbolic plasmon modes [72, 73]. In fact, many studies have unveiled the potential applications of phosphorene in nanophotonics [44, 59, 74–78], including the tunability of spontaneous emission of electric and magnetic QEs by strain engineering [58]. As a matter of fact, this tool may provide an easier control parameter in experiments compared to others, such as external fields.

In this work, we benefit from strain as an alternative method for modulating RET. By manipulating the optomechanical properties of strained phosphorene, we show that the RET rate between two QEs near phosphorene can be modified in a feasible experimental setup. We

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also highlight how the anisotropy of the optical tensors of phosphorene plays a remarkable role in this system. For QEs placed along the zigzag direction, the RET rate becomes much more sensible than along the armchair direction. Lastly, using a simple toy model, we also show that similar behavior is expected in a generic anisotropic media.

## II. MATHEMATICAL FORMALISM

The system under study is depicted in Fig. 1. The donor QE  $\mathcal{A}$  is in the excited state  $|e\rangle$  and the acceptor QE  $\mathcal{B}$  is in the ground state  $|g\rangle$ , so that the initial configuration can be represented by the vector state  $|\mathcal{A}, \mathcal{B}; \mathcal{F}_{\boldsymbol{k}p}\rangle = |e, g; 0_{\boldsymbol{k}p}\rangle$ , where  $|\mathcal{F}_{\boldsymbol{k}p}\rangle = |0_{\boldsymbol{k}p}\rangle$  denotes the absence of photons in the electromagnetic field. After evolving in time, the final state of the system becomes  $|g, e; 0_{\boldsymbol{k}p}\rangle$ . In our system, the QEs are located at positions  $\boldsymbol{r}_A = (x_A, y_A, z_A)$  and  $\boldsymbol{r}_B = (x_B, y_B, z_B)$   $(x_B - x_A =: x$  and  $y_B - y_A =: y)$  above a half-space region formed by a phosphorene sheet grown on top of a substrate made of silicon carbide (SiC). The presence of the substrate allows the application of strain to the phosphorene, illustrated along the x-direction in Fig. 1.

The optical properties of this medium are encoded in the Fresnel reflection matrix

$$\mathbb{R} = \sum_{\alpha,\beta \in \{s,p\}} r^{\beta,\alpha} \epsilon^+_{\alpha} \otimes \epsilon^-_{\beta}, \qquad (1)$$

where the indices s and p correspond to the TE and TM modes of the electromagnetic field, respectively [79]. We define the unitary vectors

$$\boldsymbol{\epsilon}_{s}^{+} = \boldsymbol{\epsilon}_{s}^{-} = \frac{-k_{y}\hat{x} + k_{x}\hat{y}}{k_{\parallel}},\tag{2}$$

$$\boldsymbol{\epsilon}_p^{\pm} = \frac{\pm ck_z(k_x\hat{x} + k_y\hat{y}) + ck_{\parallel}^2\hat{z}}{k_{\parallel}\omega}, \qquad (3)$$

where  $\omega = 2\pi c/\lambda$  is the angular frequency of the electromagnetic mode with wavelength  $\lambda$  and  $\mathbf{k}_{\parallel} = k_x \hat{x} + k_y \hat{y}$ .



Figure 1. Two QEs separated by a distance r and both at a distance z from a phosphorene/SiC interface, in which uniaxial strain may be applied. In this sketch, strain  $\epsilon_x$  is applied along the x-direction (armchair).

To calculate the RET rate, we use the dyadic Green function formalism by solving the Helmholtz equation

$$[(\boldsymbol{\nabla}_{\boldsymbol{r}} \times \boldsymbol{\nabla}_{\boldsymbol{r}} \times) - k^2(\boldsymbol{r}, \omega)] \mathbb{G}(\boldsymbol{r}, \boldsymbol{r}'; \omega) = \delta(\boldsymbol{r} - \boldsymbol{r}') \mathbb{1} \quad (4)$$

for the planar geometry described above [7, 80], where  $k^2(\omega, \mathbf{r}) = \epsilon(\omega, \mathbf{r})\omega^2/c^2$  and  $\epsilon(\omega, \mathbf{r})$  is the dimensionless electrical permittivity. Considering only electric dipole transitions and modeling the emitters within the electric dipole approximation – i.e., the field obeys  $\boldsymbol{E}(\boldsymbol{r};\omega) = \mathbb{G}(\boldsymbol{r}, \boldsymbol{r}'; \omega) \cdot \boldsymbol{d}(\boldsymbol{r}'; \omega)$  –, the normalized RET rate is

$$\frac{\Gamma_{\text{RET}}}{\Gamma_{\text{RET}}^{(0)}} = \frac{\left|\boldsymbol{d}_{B}^{eg} \cdot \mathbb{G}(\boldsymbol{r}_{B}, \boldsymbol{r}_{A}; \omega) \cdot \boldsymbol{d}_{A}^{ge}\right|^{2}}{\left|\boldsymbol{d}_{B}^{eg} \cdot \mathbb{G}^{(0)}(\boldsymbol{r}_{B}; \boldsymbol{r}_{A}; \omega) \cdot \boldsymbol{d}_{A}^{ge}\right|^{2}},$$
(5)

where  $\Gamma_{\text{RET}}^{(0)}$  stands for the RET rate in free space,  $\omega$  is the QEs transition frequency and  $d_{A,B}^{ij} = \langle i, j; 0_{kp} | \hat{d}_{A,B} | j, i; 0_{kp} \rangle$  are matrix elements of the electric dipole operator that describe the atomic transition.

One may express the dyadic Green function  $\mathbb{G}(\mathbf{r}_B, \mathbf{r}_A; \omega)$  as a sum of its free space contribution  $\mathbb{G}^{(0)}(\mathbf{r}_B, \mathbf{r}_A; \omega)$  and its scattered part  $\mathbb{G}^{(S)}(\mathbf{r}_B, \mathbf{r}_A; \omega)$ , such that

$$\mathbb{G}(\mathbf{r}_B, \mathbf{r}_A; \omega) = \mathbb{G}^{(0)}(\mathbf{r}_B, \mathbf{r}_A; \omega) + \mathbb{G}^{(S)}(\mathbf{r}_B, \mathbf{r}_A; \omega). \quad (6)$$

The free space Green function is obtained from [7]

$$\mathbb{G}^{(0)}(\boldsymbol{r},\boldsymbol{r}';\omega) = \left[\mathbb{1} + \frac{1}{k(\boldsymbol{r},\omega)}\nabla_{\boldsymbol{r}}\nabla_{\boldsymbol{r}'}\right]G_0(\boldsymbol{r},\boldsymbol{r}';\omega), \quad (7)$$

where  $G_0(\mathbf{r}, \mathbf{r}'; \omega) = (4\pi |\mathbf{r} - \mathbf{r}'|)^{-1} e^{ik(\mathbf{r}, \omega)|\mathbf{r} - \mathbf{r}'|}$ , while the scattered Green function can be written as

$$\mathbb{G}^{(S)}(\boldsymbol{r}_B, \boldsymbol{r}_A; \omega) = \frac{i}{2} \int \frac{d^2 \boldsymbol{k}_{\parallel}}{(2\pi)^2} \mathbb{R} \frac{\mathrm{e}^{i[\boldsymbol{k}_{\parallel} \cdot (\boldsymbol{r}_B - \boldsymbol{r}_A) + k_z(z_A + z_B)]}}{k_z}.$$
(8)

Throughout this paper, we assume that both transition dipole moments are oriented along the z-axis, thereby yielding

$$\mathbb{G}_{zz}^{(0)}(\boldsymbol{r}_B, \boldsymbol{r}_A; \omega) = \frac{\mathrm{e}^{i\omega r/c}}{4\pi r} \left[ 1 - \left(\frac{c}{\omega r}\right)^2 + \frac{ic}{\omega r} \right], \quad (9)$$

where  $r := |\boldsymbol{r}_B - \boldsymbol{r}_A|$ , and

$$\mathbb{G}_{zz}^{(S)}(\boldsymbol{r}_{B},\boldsymbol{r}_{A};\omega) = \frac{ic^{2}}{4\pi} \int d^{2}\mathbf{k}_{\parallel} k_{\parallel}^{2} r^{p,p} \\
\times \frac{\mathrm{e}^{i[\mathbf{k}_{\parallel} \cdot (\mathbf{r}_{B} - \mathbf{r}_{A}) + k_{z}(z_{B} + z_{A})]}}{\omega^{2}k_{z}} .$$
(10)

In this situation, the normalized RET rate can be cast into the form

$$\frac{\Gamma_{\text{RET}}}{\Gamma_{\text{RET}}^{(0)}} = \left| 1 + \frac{\mathbb{G}_{zz}^{(S)}(\mathbf{r}_B, \mathbf{r}_A; \omega)}{\mathbb{G}_{zz}^{(0)}(\mathbf{r}_B, \mathbf{r}_A; \omega)} \right|^2.$$
(11)

Generalization to other dipole orientations is straightforward and follows analogously.

#### III. CONTROLLING RET WITH STRAINED PHOSPHORENE

The conductivity tensor of strained phosphorene reads

$$\overleftarrow{\boldsymbol{\sigma}}(\omega,\epsilon_{\mu}) = \begin{bmatrix} \sigma_{xx}(\omega,\epsilon_{\mu}) & 0\\ 0 & \sigma_{yy}(\omega,\epsilon_{\mu}) \end{bmatrix}, \quad (12)$$

where  $\epsilon_{\mu}$  ( $\mu = x, y, z$ ) is the uniform strain applied along the  $\mu$ -direction, and the longitudinal conductivities along the x and y axes are computed using linear response theory (see Appendix A for more details).

#### A. RET on relaxed phosphorene

For now, we will be concerned with how phosphorene influences the RET rate without applying strain. In addition, to explore the impacts that the anisotropy of phosphorene may have on the RET rate, we analyze different configurations of the system: (i) separating the QEs along the armchair direction, i.e., maintaining y = 0and varying x [Figs. 2(a) and 2(b)], and (ii) separating the QEs along the zigzag direction, i.e., maintaining x = 0 and varying y [Figs. 2(c) and 2(d). This analysis is carried out for different distances z between the emitters and phosphorene and for two transition wavelengths ( $\lambda = 1.5, 10 \ \mu m$ ). The Fermi energy is set at  $E_{\rm F} = 0.7 \ {\rm eV}$ and we used the energy scales associated with the electronic scattering process  $\eta_1 = \eta_2 = 25 \ {\rm meV}$  [58] in all the results presented in this paper.

We call the reader's attention to three points. (i) All plots obey the limit that the normalized RET rate must converge to 1 as x and y tend to 0. The closer the QEs are to each other, the less relevant the effects of phosphorene on the energy transfer process, as expected. (ii) All curves have an oscillation pattern, commonly present in previous works dealing with RET near non-ideal surfaces



Figure 2. Normalized RET rate as a function of the distance between the QEs placed along the x-axis [panels (a) and (b)] and y-axis [panels (c) and (d)]. We set  $\lambda = 1.5 \ \mu m$  in the first row and  $\lambda = 10 \ \mu m$  in the second row.



Figure 3. Normalized RET rate as a function of z for different distances between the QEs placed along the x-axis [panels (a) and (b)] and y-axis [panels (c) and (d)]. We set  $\lambda = 1.5 \ \mu m$  in the first row and  $\lambda = 10 \ \mu m$  in the second row.

[45, 81–83]. (*iii*) While the normalized RET rate barely changes for QEs separated along the x-axis (armchair), it is drastically changed when the separation is along the y-axis (zigzag).

In Fig. 3, we do the complementary plots, fixing the distance x or y between both QEs and varying the distance between them to the phosphorene sheet. In this case, the analog of comment (i) is that the normalized RET rate must converge to 1 when  $z \to \infty$ , as the influence of phosphorene is progressively reduced. These results also underline how the position of the QEs to the phosphorene is crucial and may give rise to an enormous difference in the normalized RET rate. Interestingly, a very simplified model for the conductivities suggests that this disparity is predicted whenever the 2D medium near the emitters is anisotropic, as we will see in Sec. IV.

#### B. RET on strained phosphorene

We now account for the effects of uniaxial strain in Fig. 4, evaluating the variation of the RET rate as a function of the distance parameters for different strain values. We have chosen to discuss the strain  $\epsilon_y$  being applied to the zigzag direction in phosphorene, but the analysis for  $\epsilon_x$  follows analogously. From Fig. 4, it is clearly seen that the RET rate is poorly influenced by strain when the QEs are separated along the x-axis, but it is quite sensitive when they are along the y-axis, according to the discussions in Sec. III A.

Figure 5 presents the modification in the RET rate as we continuously tune strain, revealing a strong nonmonotonic character. In all plots, we draw dashed lines at  $\epsilon_y = 11.8\%$ , highlighting the strain value from which phosphorene exhibits a change from the metallic to the insulating regime (see Appendix A). This regime, in turn, gives rise to a discontinuous change in the RET rate. From these results, we conclude that strain can be a resourceful tool for controlling RET, as it drastically alters the RET rate, especially for short distances.



Figure 4. Normalized RET rate as a function of the distance parameters for  $\lambda = 10 \ \mu m$  and different strain values. In the first column, we take  $z = 0.01\lambda$  and vary (a) x, with y = 0, and (b) y, with x = 0. For the second column, we vary the distance z between the QEs and phosphorene, setting (c)  $x = 0.1\lambda$ , with y = 0, and (d)  $y = 0.1\lambda$ , with x = 0.



Figure 5. Normalized RET rate as a function of strain as we change the separation of the QEs. We set  $z = 0.03\lambda$  in panels (a) and (b), and  $y = 0.5\lambda$  in panels (c) and (d). In all plots,  $\lambda = 10 \ \mu m$  and we draw a dashed line at  $\epsilon_y =$ 11.8%, which separates the metallic and insulating regimes when  $E_{\rm F} = 0.7$  eV.

# IV. ANISOTROPIC EFFECTS ON RET

In Sec. III, we showed that the RET rate of two QEs near phosphorene remains virtually unchanged when we separate them along the armchair direction, but is drastically altered when placed along the zigzag direction. In this section, we argue that this difference is not specific to phosphorene but rather a general property of anisotropic media.

We consider a generic anisotropic 2D material grown above a SiC substrate and assume that its longitudinal conductivity along x-direction takes the generic value  $\bar{\sigma}_{xx} = \sigma_0 (0.33 + i1.63)$ , where  $\sigma_0 = e^2/\hbar$ . In this toy model, we suppose that the conductivity along the y-direction is related to  $\bar{\sigma}_{xx}$  by an anisotropy parameter F, i.e.,  $\bar{\sigma}_{yy}(F) = F\bar{\sigma}_{xx}$ . The conductivity tensor reads

$$\overleftarrow{\boldsymbol{\sigma}}_{\text{toy}}(F) = \begin{bmatrix} \bar{\sigma}_{xx} & 0\\ 0 & F \bar{\sigma}_{xx} \end{bmatrix} .$$
(13)

For F = 1, we recover the case of an isotropic 2D material. This simple toy model allows us to isolate the impacts of the interface anisotropy on RET.

In Fig. 6, we portray the normalized RET rate for two emitters with  $\lambda = 1.5 \,\mu$ m placed at a distance z above the anisotropic 2D material. We explore two scenarios. In the first, the emitters are separated along the x-direction [Figs. 6(a) and 6(b)], and, in the second case, the emitters are separated along the y-direction [Figs. 6(c) and 6(d)]. For F = 1, the normalized RET rate gives the same value for both scenarios, as expected for an isotropic interface. However, a slight variation in F reveals that the RET rate exhibits an anisotropic character, indicating that the RET rate generally depends on the direction in which the emitters are separated. Consequently, a large variation in RET and a greater sensitivity in the parameter variation can be expected when both QEs are



Figure 6. Normalized RET rate as a function of the distance between the QEs near anisotropic 2D material/SiC interface separated along the x-axis [panels (a) and (b)] and along the y-axis [panels (c) and (d)], for different values of F. We set  $z = 0.1\lambda$  in the first row and  $z = \lambda$  in the second one. In all cases,  $\lambda = 1.5 \ \mu m$ .

separated along the x-direction (y-direction) if F > 1(F < 1). The conductivity model in Eq. (13) captures the global effects of anisotropy, which is also present in other realistic systems pertinent to nanophotonics, such as carbon nanotubes metasurfaces [84] and a broad class of 2D materials [85].

# V. FINAL REMARKS AND CONCLUSIONS

In summary, we showed that RET between QEs can be substantially enhanced or suppressed when brought close to a phosphorene sheet. We demonstrated that the anisotropy of phosphorene's optical tensors leads to a drastically different RET rate depending on whether the QEs are separated along the armchair or zigzag directions of phosphorene. In addition to its inherent anisotropic response, phosphorene's structure allows the application of uniform strain, enabling active and non-monotonical modulation of the RET rate within the scope of experimental realization. Moreover, through a simplified toy model, we verified that this anisotropic signature in the RET rate is envisioned for general anisotropic 2D media. Altogether, we believe that this anisotropy may be relevant for designing efficient energy-harvesting mechanisms in future nanophotonic devices, especially in view of the fact that other 2D materials also present an anisotropic band structure [85] and many of them exhibit straintunable optical properties. Our findings motivate further studies on strain engineering in the pool of anisotropic 2D materials and their use in nanophotonic effects.

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### Appendix A: Conductivities of strained phosphorene

In this work, we model the electronic structure of phosphorene using a two-band tight-binding model [67, 71]. The effect of the uniaxial strain is included following Harrison's prescription [70]. The optical conductivities along the x- and y- directions are computed within the linear response theory and consist of two contributions: interband and intraband terms, such that  $\sigma_{\mu\mu}(\omega) =$  $\sigma_{\mu\mu}^{\text{Inter}}(\omega) + \sigma_{\mu\mu}^{\text{Intra}}(\omega)$ , where  $\mu = \{x, y\}$ . A detailed review of this approach is provided in Ref. [58].

In Figs. 7 and 8, we show the real and imaginary parts of the optical conductivity of phosphorene under different values of uniaxial strain  $\epsilon_y$  applied along the



Figure 7. Real and imaginary parts of phosphorene's optical conductivity in the insulator regime ( $E_{\rm F}$  always inside the energy gap) as functions of frequency under the effect of different strains.



Figure 8. Real and imaginary parts of phosphorene's optical conductivity for  $E_{\rm F} = 0.7$  eV as functions of frequency under the effect of different strains.

y-direction. In Fig. 7, we display the results where the Fermi energy  $E_{\rm F}$  is forced to be in the middle of the energy bandgap, and only the interband term contributes to the optical conductivity. In Fig. 8, we display the results for  $E_{\rm F} = 0.7$  eV. In this situation, a Drude peak at low frequencies, associated with the intraband contribu-

tion, appears when  $E_{\rm F}$  crosses an electronic energy band of phosphorene (for  $E_{\rm F} = 0.7$  eV, the Drude peak occurs when  $\epsilon_y < 11.8\%$ ) [58]. In the main text, we use the conductivities reported in Fig. 8.

## Appendix B: Strained phosphorene reflection coefficients

To enable the application of uniaxial strain on phosphorene, we assume that it is grown on a slab of SiC, whose electrical permittivity can be described by a simple Drude-Lorentz model [86], such that

$$\varepsilon_{\rm SiC}(\omega) = \varepsilon_{\infty} \left( 1 + \frac{\omega_L^2 - \omega_T^2}{\omega_T^2 - \omega^2 - i\omega\gamma_{\rm SiC}} \right) \,, \qquad (B1)$$

where  $\varepsilon_{\infty} = 6.7\varepsilon_0$ ,  $\omega_L = 182.7 \times 10^{12} \text{ rad/s}$ ,  $\omega_T = 149.5 \times 10^{12} \text{ rad/s}$  and  $\gamma_{\text{SiC}} = 0.9 \times 10^{12} \text{ rad/s}$  [87].

The Fresnel reflection coefficients of the phosphorene/SiC interface

$$r^{p,p}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu}) = \frac{\Delta_{+}^{T}\Delta_{-}^{L} + \Lambda^{2}}{\Delta_{+}^{T}\Delta_{+}^{L} + \Lambda^{2}}, \qquad (B2)$$

$$r^{s,s}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu}) = -\frac{\Delta_{-}^{T}\Delta_{+}^{L} + \Lambda^{2}}{\Delta_{+}^{T}\Delta_{+}^{L} + \Lambda^{2}}$$
(B3)

can be easily obtained by solving Maxwell's equations with appropriate boundary conditions [34], where

$$\Delta_{\pm}^{T}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu}) = \frac{1}{\mu_{0}} \bigg[ k_{z2}(\boldsymbol{k}_{\parallel},\omega)\mu_{1} \pm k_{z1}(\boldsymbol{k}_{\parallel},\omega)\mu_{1} \\ + \omega\mu_{1}\mu_{2}\sigma_{T}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu}) \bigg], \qquad (B4)$$

$$\Delta_{\pm}^{L}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu}) = \frac{1}{\varepsilon_{0}} \bigg[ k_{z1}(\boldsymbol{k}_{\parallel},\omega)\varepsilon_{2} \pm k_{z2}(\boldsymbol{k}_{\parallel},\omega)\varepsilon_{1} \\ + k_{z1}(\boldsymbol{k}_{\parallel},\omega)k_{z2}(\boldsymbol{k}_{\parallel},\omega)\frac{\sigma_{L}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu})}{\omega} \bigg],$$
(B5)  
$$\Lambda^{2}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu}) = -\frac{\mu_{1}\mu_{2}}{\varepsilon_{0}^{2}}k_{z1}(\boldsymbol{k}_{\parallel},\omega)k_{z2}(\boldsymbol{k}_{\parallel},\omega)\sigma_{LT}^{2}(\boldsymbol{k}_{\parallel},\omega,\epsilon_{\mu})$$
(B6)

In the previous equations,  $\epsilon_{\mu}$  is the uniaxial strain applied in phosphorene along the  $\mu$ -direction,  $\sigma_L = (k_x^2 \sigma_{xx} + k_y^2 \sigma_{yy})/k_{\parallel}^2$ ,  $\sigma_T = (k_y^2 \sigma_{xx} + k_x^2 \sigma_{yy})/k_{\parallel}^2$ , and  $\sigma_{LT} = k_x k_y (\sigma_{yy} - \sigma_{xx})/k_{\parallel}^2$ . Additionally,  $k_{zj} = \sqrt{\omega^2 \epsilon_j \mu_j - k_{\parallel}^2}$ . For our system, the first medium is vacuum ( $\varepsilon_1 = \varepsilon_0$ ,  $\mu_1 = \mu_0$ ) and the second is SiC ( $\varepsilon_2 = \varepsilon_{\rm SiC}(\omega)$ ,  $\mu_2 = \mu_0$ ).

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